

isc Silicon PNP Power Transistor

DESCRIPTION

- · Collector-Emitter Breakdown Voltage
 - : V_{(BR)CEO}= -30V(Min)
- Good Linearity of hFE
- Complement to Type KSC1173
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

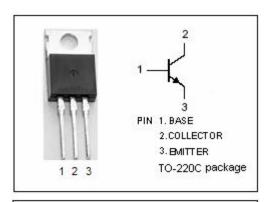


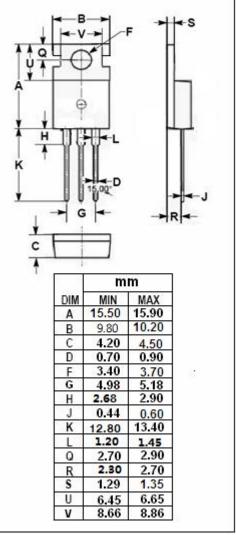
APPLICATIONS

- · Low frequency power amplifier applications.
- Power regulator

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|--|-------|---------------|
| V _{CBO} | Collector-Base Voltage | -30 | V |
| Vceo | Collector-Emitter Voltage | -30 | V |
| V _{EBO} | Emitter-Base Voltage | -5 | V |
| lc | Collector Current-Continuous | -3 | А |
| lE | Emitter Current-Continuous | -3.0 | Α |
| Pc | Total Power Dissipation @ T _C =25°C | 10 | W |
| TJ | Junction Temperature 15 | | ${\mathbb C}$ |
| T _{stg} | Storage Temperature Range -55~ | | ${\mathbb C}$ |







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KSA473

ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | MAX | UNIT |
|-----------------------|--------------------------------------|---|-----|------|------|------|
| V _(BR) CEO | Collector-Emitter Breakdown Voltage | I _C = -10 mA; I _B = 0 | -30 | | | V |
| V _{(BR)EBO} | Emitter-Base Breakdown Voltage | I _E = -0.1mA; I _C = 0 | -5 | | | V |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = -2A; I _B = -0.2A | | | -0.8 | V |
| V _{BE(on)} | Base-Emitter On Voltage | I _C = -0.5A; V _{CE} = -2V | | | -1.0 | V |
| I _{CBO} | Collector Cutoff Current | V _{CB} = -20V; I _E = 0 | | | -1.0 | μА |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = -5V; I _C = 0 | | | -1.0 | μА |
| h _{FE-1} | DC Current Gain | I _C = -0.5A; V _{CE} = -2V | 70 | | 240 | |
| h _{FE-2} | DC Current Gain | I _C = -2.5A; V _{CE} = -2V | 25 | | | |
| f _T | Current-Gain—Bandwidth Product | I _E = 0.5A; V _{CE} = -2V | | 100 | | MHz |

♦ h_{FE-1} Classifications

| 0 | Y |
|--------|---------|
| 70-140 | 120-240 |

Notice:

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